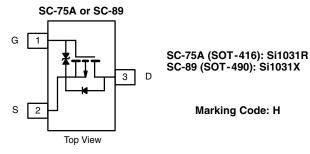
HALOGEN

FREE



P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (mA)		
- 20	8 at V _{GS} = - 4.5 V	- 150		
	12 at V _{GS} = - 2.5 V	- 125		
	15 at V _{GS} = - 1.8 V	- 100		
	20 at V _{GS} = - 1.5 V	- 30		



Ordering Information:

Si1031R-T1-GE3 (SC-75A, Lead (Pb)-free and Halogen-free) Si1031X-T1-GE3 (SC-89, Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- · High-Side Switching
- Low On-Resistance: 8 Ω
- Low Threshold: 0.9 V (typ.)
- Fast Switching Speed: 45 ns
- TrenchFET[®] Power MOSFETs: 1.5 V Rated
- ESD Protected: 2000 V
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- Battery Operated Systems
- Power Supply Converter Circuits
- · Load/Power Switching Cell Phones, Pagers

BENEFITS

- · Ease in Driving Switches
- · Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Battery Voltage Operation

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)							
		Symbol	Si1031R		Si1031X		
Parameter	5 s		Steady State	5 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	- 20				V
Gate-Source Voltage		V_{GS}	± 6				V
0 "	T _A = 25 °C	,	- 150	- 140	- 165	- 155	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C	I _D	- 110	- 100	- 150	- 125	
Pulsed Drain Current ^a		I _{DM}	- 500		- 600		mA
Continuous Source Current (Diode Conduction) ^a		I _S	- 250	- 200	- 340	- 240	
	T _A = 25 °C	_	280	250	340	300	mW
Maximum Power Dissipation ^a	T _A = 85 °C		145	130	170	150	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150				°C
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000				V

Notes:

a. Surface mounted on FR4 board.

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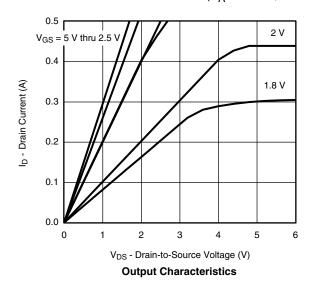
SPECIFICATIONS (T _A = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.40		- 1.2	V	
Cata Badist saliana	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 2.8 \text{ V}$ ±		± 0.5	± 1.0	μА	
Gate-Body Leakage		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$ ± 1.0 \pm		± 2.0		
Zoro Cata Valtaga Drain Current	lana	V _{DS} = - 16 V, V _{GS} = 0 V		- 1	- 500	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 16 V, V _{GS} = 0 V, T _J = 85 °C			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 200			mA	
		V _{GS} = - 4.5 V, I _D = - 150 mA			8		
	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 125 mA			12	0	
Drain-Source On-State Resistance ^a		V _{GS} = - 1.8 V, I _D = - 100 mA			15	Ω	
		V _{GS} = - 1.5 V, I _D = - 30 mA			20		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = 150 mA		0.4		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 150 mA, V _{GS} = 0 V			- 1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			1500			
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -150 \text{ mA}$		150		рC	
Gate-Drain Charge	Q _{gd}			450		1	
Turn-On Delay Time	t _{d(on)}				55		
Rise Time	t _r	$V_{DD} = -10 \text{ V}, R_L = 65 \Omega$		_	30	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 150 mA, V_{GEN} = - 4.5 V, R_g = 10 Ω			60	115	
Fall Time	t _f				30		

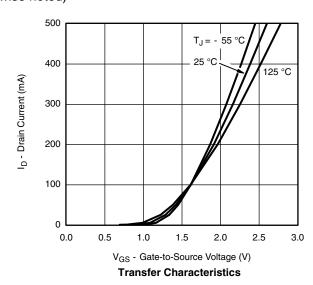
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

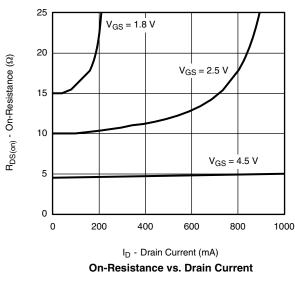


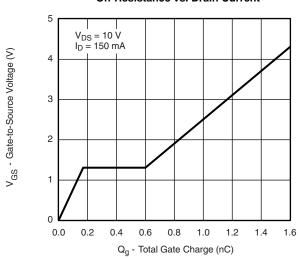


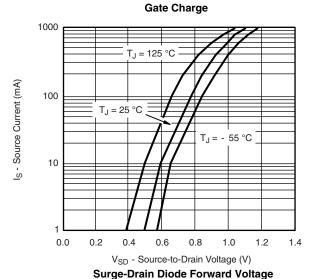


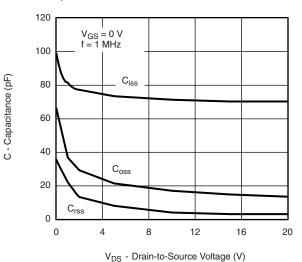


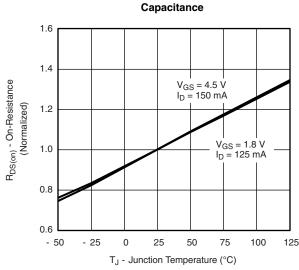
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

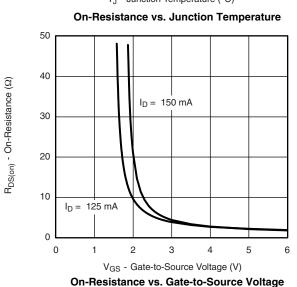








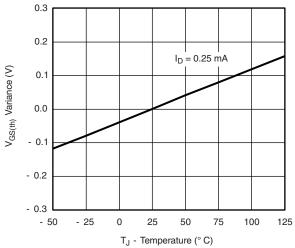


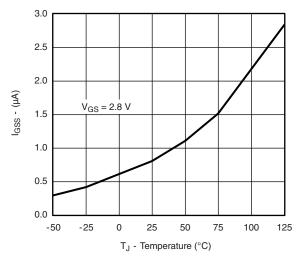


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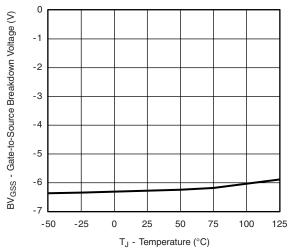
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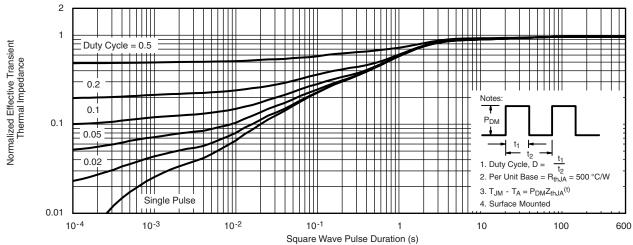


Threshold Voltage Variance vs. Temperature

I_{GSS} vs. Temperature





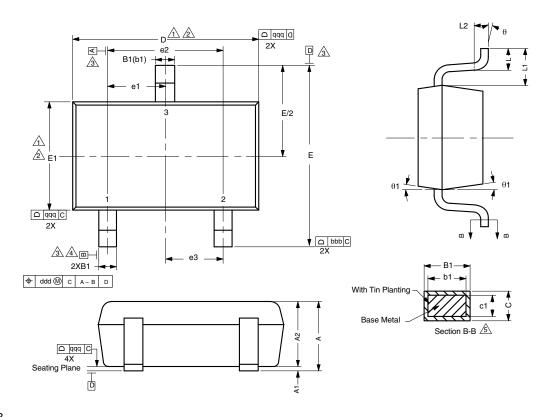


Normalized Thermal Transient Impedance, Junction-to-Ambient (SC-75A, Si1031R Only)

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71171.



SC-75A: 3 Leads



DWG: 5868

Notes

Dimensions in millimeters will govern.

- Dimension D does not include mold flash, protrusions or gate burrs. Mold flash protrusions or gate burrs shall not exceed 0.10 mm per end. Dimension E1 does not include Interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.10 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.
- ②Datums A, B and D to be determined 0.10 mm from the lead tip.

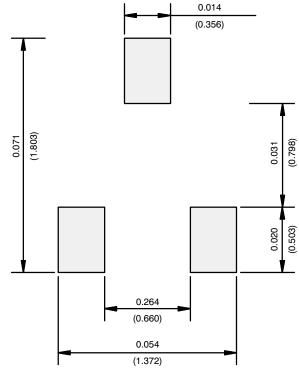
 4\text{Terminal positions are shown for reference only.}
- These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIMENSIONS	TOLERANCES		
aaa	0.10		
bbb	0.10		
ccc	0.10		
ddd	0.10		

DIM.	N	NOTE		
	MIN.	NOM.	MAX.	NOTE
Α	-	-	0.80	
A1	0.00	-	0.10	
A2	0.65	0.70	0.80	
B1	0.19	-	0.24	5
b1	0.17	-	0.21	
С	0.13	-	0.15	5
c1	0.10	-	0.12	5
D	1.48	1.575	1.68	1, 2
Е	1.50	1.60	1.70	
E1	0.66	0.76	0.86	1, 2
e1				
e2				
e3				
L	0.15 0.205 0.30			
L1				
L2				
q	0°	- 8°		
q1	4°	- 10°		



RECOMMENDED MINIMUM PADS FOR SC-75A: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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